

RoHS COMPLIANT

HALOGEN

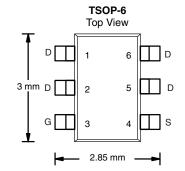
FREE

(1, 2, 5, 6)

Vishay Siliconix

N-Channel 100 V (D-S) MOSFET

MOSFET PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (Ω) Max.	I _D (A) ^a	Q _g (Typ.)		
	0.126 at V _{GS} = 10 V	3.8			
100	0.147 at V _{GS} = 6 V	3.5	2.9 nC		
	0.189 at V _{GS} = 4.5 V	3.1			

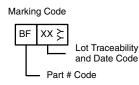


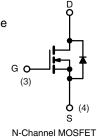
FEATURES

- TrenchFET[®] Power MOSFET
- 100 % R_g and UIS Tested Material categorization: For definitions of compliance please see
- www.vishay.com/doc?99912

APPLICATIONS

- DC/DC Converters / Boost Converters •
- Load Switch
- LED Backlighting in LCD TVs
- Power Management for Mobile Computing





Ordering Information:

Si3474DV-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	100	V
Gate-Source Voltage		V _{GS}	± 20	
	T _C = 25 °C		3.8	
Continuous Drain Current (T 150 °C)	T _C = 70 °C		3	
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	I _D	2.8 ^{b, c}	
	T _C = 70 °C		2.3 ^{b, c}	A
Pulsed Drain Current (t = 100 µs)		I _{DM}	14	
Continuous Source Drain Diada Current	T _C = 25 °C	la la	3	
Continuous Source-Drain Diode Current	T _A = 25 °C	I _S	1.7 ^{b, c}	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	2.5	
Single Pulse Avalanche Energy		E _{AS}	0.31	mJ
Maximum Power Dissipation	T _C = 25 °C		3.6	
	T _C = 70 °C	PD	2.33	w
	T _A = 25 °C	'D	2 ^{b, c}	V
	T _A = 70 °C		1.3 ^{b, c}	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{b, d}	≤ 5 s	R _{thJA}	50	62.5	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	28	35	0/11

Notes:

a. Based on T_C = 25 °C.

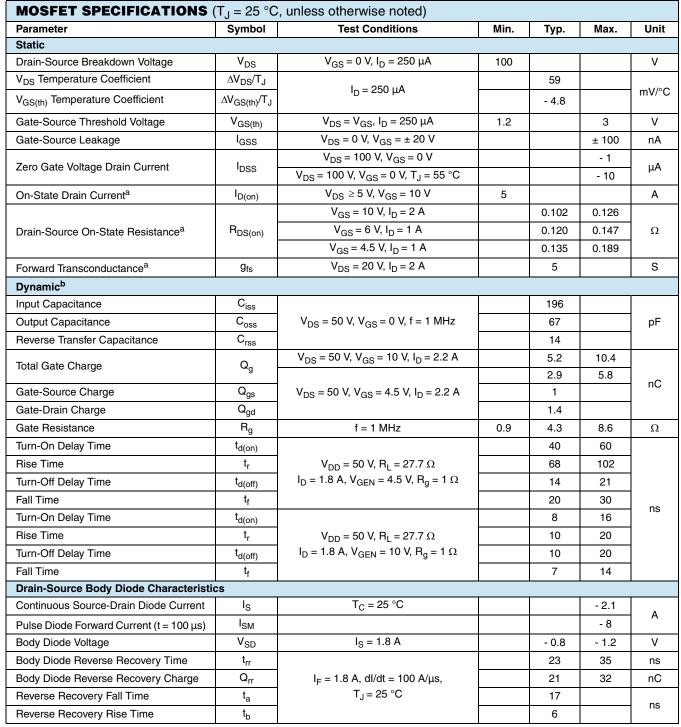
b. Surface mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. Maximum under steady state conditions is 110 °C/W.

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Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

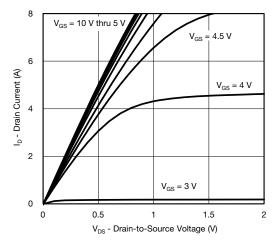
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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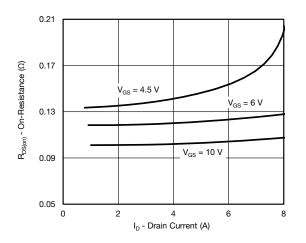


Si3474DV Vishay Siliconix

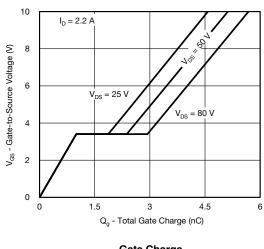
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



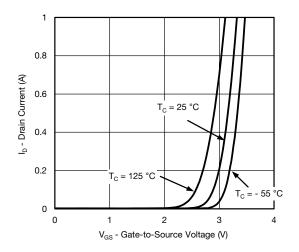




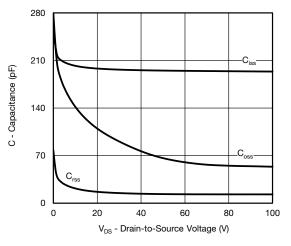
On-Resistance vs. Drain Current and Gate Voltage



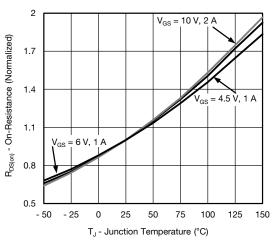
Gate Charge



Transfer Characteristics







On-Resistance vs. Junction Temperature

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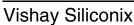
For technical questions, contact: pmostechsupport@vishay.com

www.vishay.com

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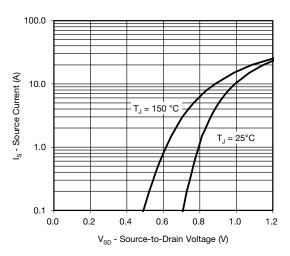
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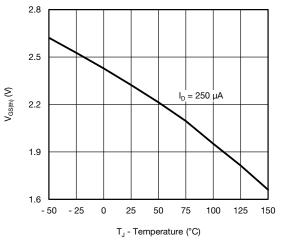




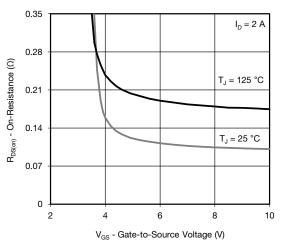
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



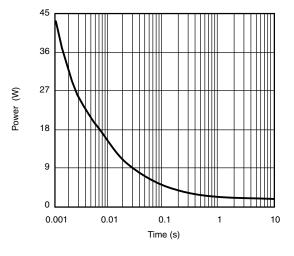
Source-Drain Diode Forward Voltage



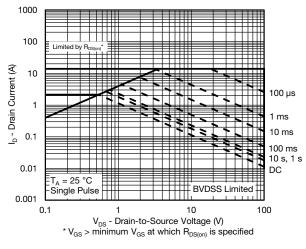
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage







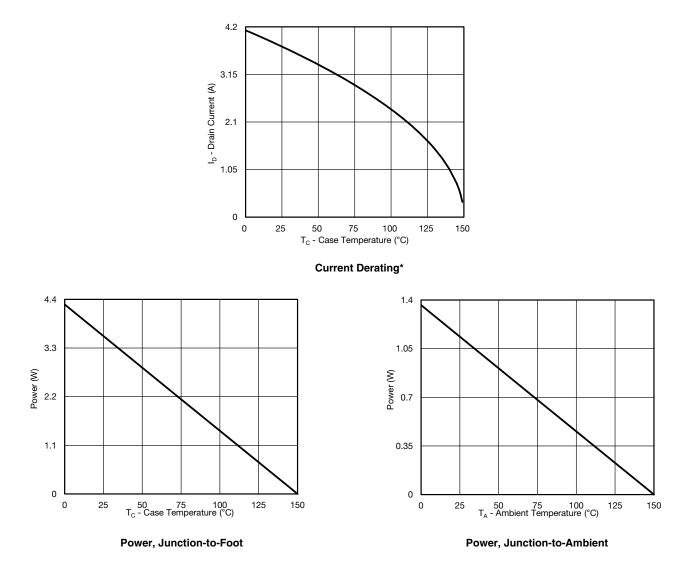
Safe Operating Area

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



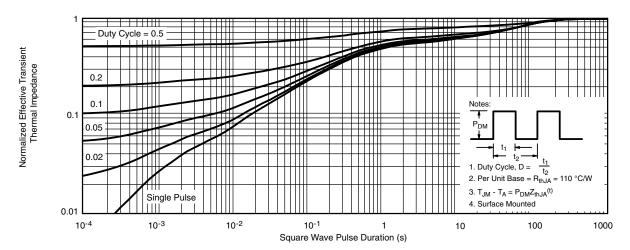
* The power dissipation P_D is based on $T_{J(max.)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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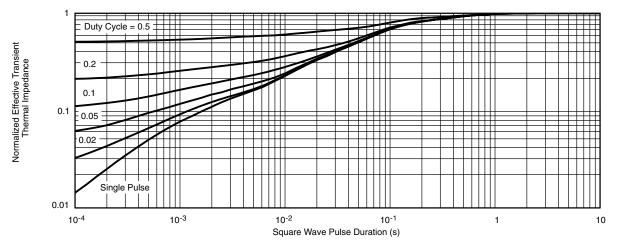


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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg262875.

www.vishay.com 6 Document Number: 62875 S13-1664-Rev. A, 29-Jul-13

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Package Information

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TSOP: 5/6-LEAD JEDEC Part Number: MO-193C









6-LEAD TSOP



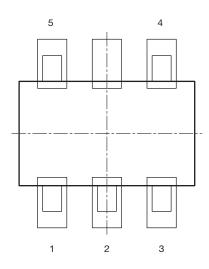
	MILLIMETERS			INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.91	-	1.10	0.036	-	0.043
A ₁	0.01	-	0.10	0.0004	-	0.004
A ₂	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
С	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
Е	2.70	2.85	2.98	0.106	0.112	0.117
E ₁	1.55	1.65	1.70	0.061	0.065	0.067
е	0.95 BSC		0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L ₁	0.60 Ref		0.024 Ref			
L ₂	0.25 BSC		0.010 BSC			
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ_1	7° Nom		7° Nom			
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540						

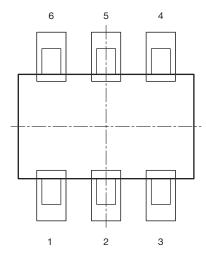
PAD Pattern



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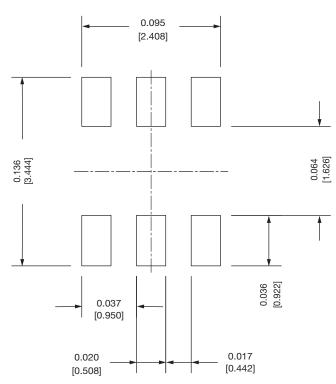
Recommended Land Pattern For TSOP-5L / TSOP-6L





TSOP 5L





Note

• All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022	
DWG: 3010	

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